



CXT7820

**SURFACE MOUNT
VERY LOW $V_{CE(SAT)}$
PNP SILICON TRANSISTOR**



SOT-89 CASE

APPLICATIONS:

- DC/DC Converters
- Voltage Clamping
- Protection Circuits
- Battery powered Cell Phones, Pagers, Digital Cameras, PDAs, Laptops, etc.

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage	80
Collector-Emitter Voltage	60
Emitter-Base Voltage	5.0
Continuous Collector Current	1.0
Peak Collector Current	2.0
Base Current	300
Power Dissipation	1.2
Operating and Storage Junction Temperature	-65 to +150
Thermal Resistance	104

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=60\text{V}$		100	nA
I_{EBO}	$V_{EB}=5.0\text{V}$		100	nA
BV_{CBO}	$I_C=100\mu\text{A}$	80		V
BV_{CEO}	$I_C=10\text{mA}$	60		V
BV_{EBO}	$I_E=100\mu\text{A}$	5.0		V
$V_{CE(SAT)}$	$I_C=100\text{mA}, I_B=1.0\text{mA}$		0.175	V
$V_{CE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$		0.18	V
$V_{CE(SAT)}$	$I_C=1.0\text{A}, I_B=100\text{mA}$		0.34	V
$V_{BE(SAT)}$	$I_C=1.0\text{A}, I_B=50\text{mA}$		1.1	V
$V_{BE(ON)}$	$V_{CE}=5.0\text{V}, I_C=1.0\text{A}$		0.9	V
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}$	200		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=500\text{mA}$	150		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{A}$	100		
f_T	$V_{CE}=10\text{V}, I_C=50\text{mA}$	150		MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$		15	pF

CentralTM Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CXT7820 is a very low $V_{CE(SAT)}$ PNP transistor designed for applications where electrical and thermal efficiency are prime requirements. Packaged in an industry standard SOT-89 case, this device brings updated electrical specifications and characteristics suitable for the most demanding designs.

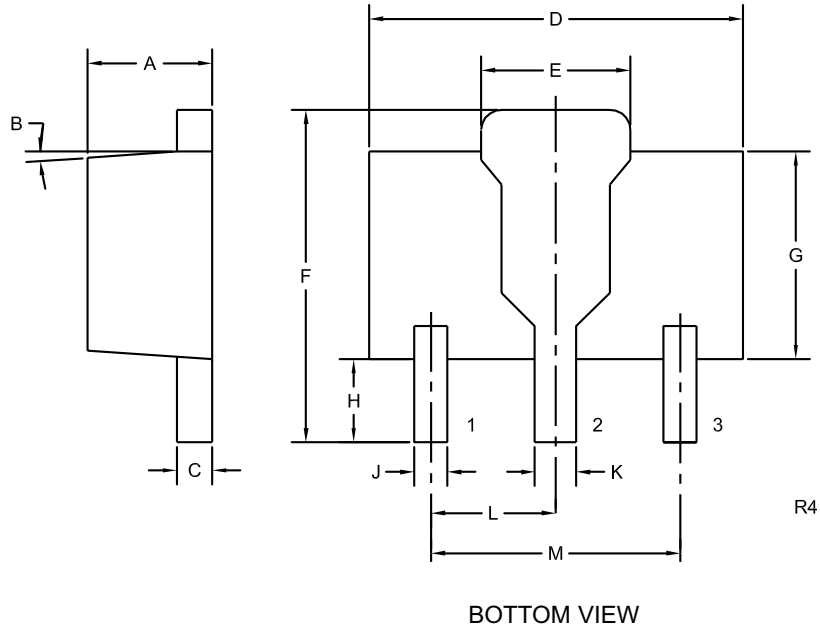
MARKING: FULL PART NUMBER

FEATURES:

- Device is **Halogen Free** by design
- High Current ($I_C=1.0\text{A}$)
- $V_{CE(SAT)}=0.34\text{V MAX @ } I_C=1.0\text{A}$
- SOT-89 surface mount package
- Complementary NPN device **CXT3820**

SYMBOL		UNITS
V_{CBO}	80	V
V_{CEO}	60	V
V_{EBO}	5.0	V
I_C	1.0	A
I_{CM}	2.0	A
I_B	300	mA
P_D	1.2	W
T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
θ_{JA}	104	$^\circ\text{C/W}$

SOT-89 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) EMITTER
- 2) COLLECTOR
- 3) BASE

MARKING:

FULL PART NUMBER

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.067	1.40	1.70
B	4°		4°	
C	0.014	0.018	0.35	0.46
D	0.173	0.185	4.40	4.70
E	0.064	0.074	1.62	1.87
F	0.146	0.177	3.70	4.50
G	0.090	0.106	2.29	2.70
H	0.028	0.051	0.70	1.30
J	0.014	0.019	0.36	0.48
K	0.017	0.023	0.44	0.58
L	0.059		1.50	
M	0.118		3.00	

SOT-89 (REV: R4)